



Product data sheet

1. General description

Ultrafast power diode in TO-263 (D2PAK) plastic package.

2. Features and benefits

- Low forward voltage drop
- Low leakage current
- Soft reverse recovery characteristics
- High thermal cycling performance

3. Applications

- Home appliance power supply
- Discontinuous Current Mode (DCM) Power Factor Correction (PFC)

4. Quick reference data

Symbol	Parameter	Conditions	Values			Unit	
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage			6	00		V
$I_{F(AV)}$	average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 150 °C; Fig. 1; Fig. 2; Fig. 3	9		A		
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t _p = 25 µs; T _{mb} ≤ 150 °C; square-wave pulse	18		A		
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4				A	
		t_{p} = 8.3 ms; $T_{j(\text{init})}$ = 25 °C; sine-wave pulse;			А		
Symbol	Parameter	Conditions			Unit		
Static ch	aracteristics						
V _F	forward voltage	I _F = 8 A; T _j = 25 °C; <u>Fig. 6</u>		-	1.05	1.3	V
		I _F = 8 A; T _j = 150 °C; <u>Fig. 6</u>		-	0.9	1.1	V
Dynamic	characteristics						
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 100 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$		-	40	75	ns

5. Pinning information

	Pinning info			
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	no connected		K – A 001aaa020
2	К	cathode[1]		001888020
3	А	anode	L	
mb	mb	mounting base; connected to cathod		

[1] It is not possible to connect to pin 2 of the TO-263 package.

6. Ordering information

Table 3. Ordering information						
Type number Package						
	Name	Description	Version			
BYV29B-600P	TO-263	plastic single-ended surface-mounted package (D2PAK); 3-leads (one lead cropped)	D2PAK			

7. Marking

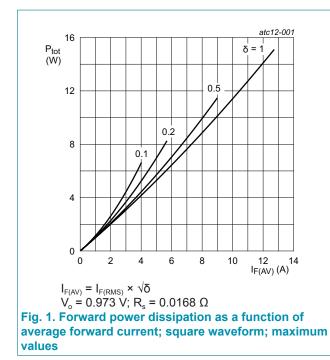
Table 4. Marking codes							
Type number	Marking codes						
BYV29B-600P	BYV29B-600P						

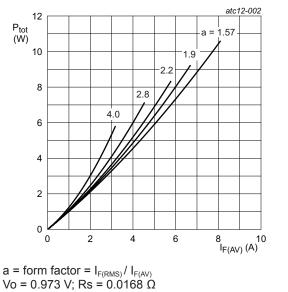
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

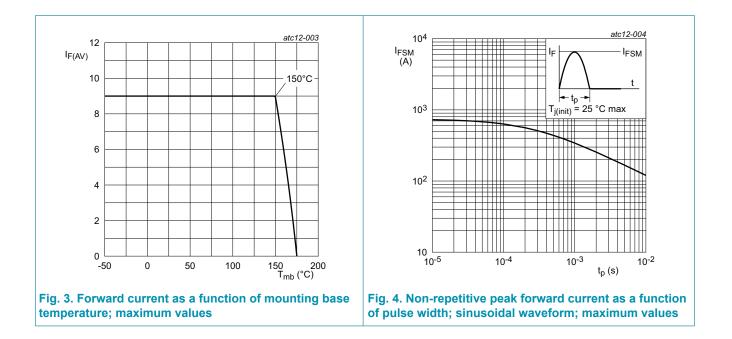
Symbol	Parameter	Conditions	Values	Unit
V_{RRM}	repetitive peak reverse voltage		600	V
$V_{\rm RWM}$	crest working reverse voltage		600	V
V _R	reverse voltage	DC	600	V
I _{F(AV)}	average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 150 °C; Fig. 1; Fig. 2; Fig. 3	9	A
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t _p = 25 µs; T _{mb} ≤ 150 °C; square-wave pulse	18	A
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	120	A
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse;	132	А
T _{stg}	storage temperature		-55 to 175	°C
Tj	junction temperature		175	°C





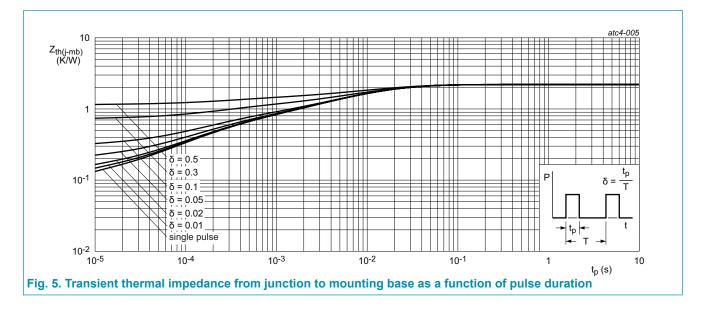
Vo = 0.973 V; Rs = 0.0168 Ω Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

BYV29B-600P Ultrafast power diode



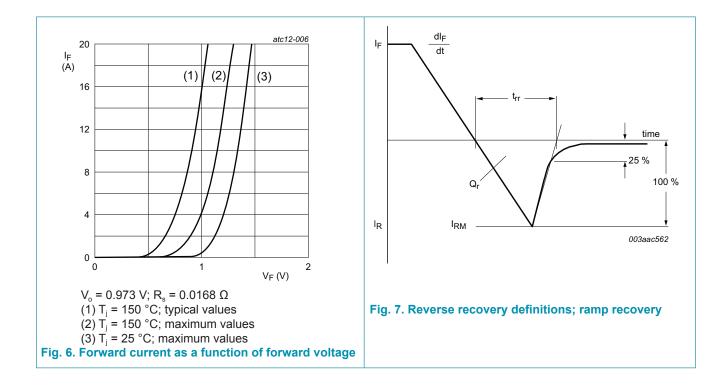
9. Thermal characteristics

Table 6. Th	ermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	<u>Fig. 5</u>	-	-	2.2	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air	-	50	-	K/W

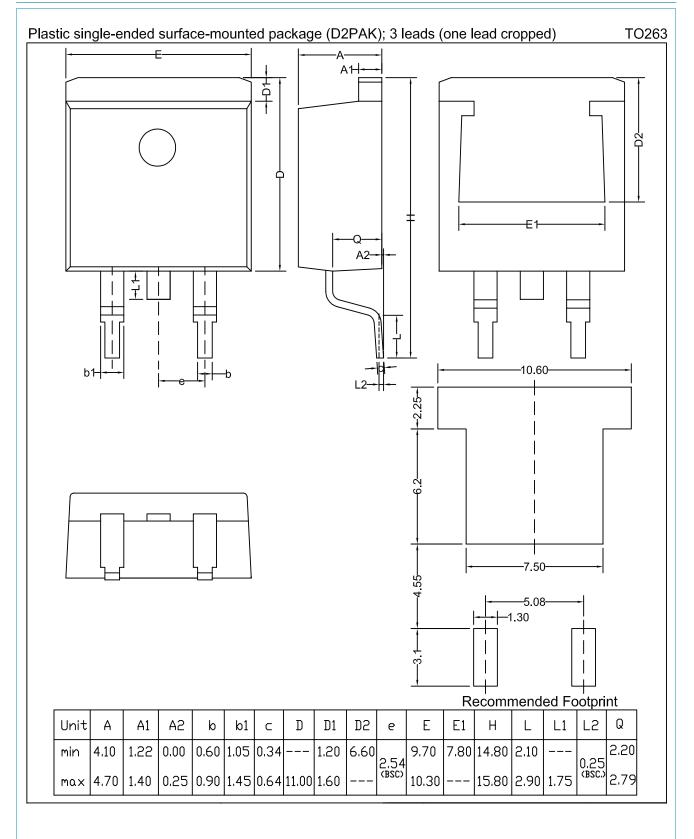


10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
V _F	forward current	I _F = 8 A; T _j = 25 °C; <u>Fig. 6</u>	-	1.05	1.3	V
		I _F = 8 A; T _j = 150 °C; <u>Fig. 6</u>	-	0.9	1.1	V
I _R	reverse current	V _R = 600 V; T _j = 25 °C	-	-	10	μA
		V _R = 600 V; T _j = 150 °C	-	-	0.4	mA
Dynamic	characteristics	·,				
Q _r	reverse charge	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 100 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	55	-	nC
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 100 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	40	75	ns
I _{RM}	peak reverse recovery current	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 50 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	1.9	-	A
		I _F = 1 A; V _R = 30 V; dI _F /dt = 100 A/µs; T _i = 25 °C; <u>Fig. 7</u>	-	2.8	-	А



11. Package outline



BYV29B-600P Product data sheet

BYV29B-600P

Ultrafast power diode

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

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13. Contents

1.	General description	1
2.	Features and benefits	1
3.	Applications	1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Marking	2
8.	Limiting values	3
9.	Thermal characteristics	5
10.	Characteristics	6
11.	Package outline	7
12.	Legal information	8
13.	Contents	10

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